TOSHIBA 1SV242

TOSHIBA VARIABLE CAPACITANCE DIODE SILICON EPITAXIAL PLANAR TYPE

1 S V 2 4 2

TV VHF WIDE BAND TUNING

High Capacitance Ratio : C1V/C28V=14.5 (Typ.)

Low Series Resistance : $r_S = 0.65\Omega$ (Typ.)

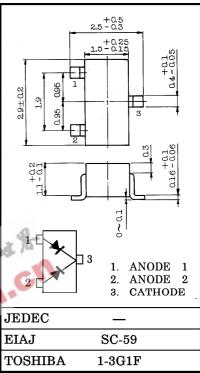
Excellent C-V Characteristics, and Small Tracking Error.

Small Package

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Reverse Voltage	v_{R}	30	V
Peak Reverse Voltage	$v_{ m RM}$	$ m (R_L = 10 k\Omega)$	V
Junction Temperature	T_{j}	12 5	$^{\circ}\mathrm{C}$
Storage Temperature Range	$\mathbf{T_{stg}}$	-55~125	$^{\circ}\mathrm{C}$

Unit in mm



Weight: 0.013g

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Reverse Voltage	$v_{\mathbf{R}}$	$I_R = 1 \mu A$		30		_	V
Reverse Current	$I_{ m R}$	$V_{ m R}$ = 28 V			1	10	nA
Capacitance	C1V	$V_R = 1V$, $f = 1MHz$	(Note 1)	36	39	42	рF
Capacitance	C28V	$V_R = 28V$, $f = 1MHz$	(Note 1)	2.43	2.7	3.0	рF
Capacitance Ratio	C1V / C28V	_	(Note 1)	13.4	14.5	_	1
Series Resistance	$r_{ m S}$	$V_R = 5V, f = 470MHz$	(Note 1)	_	0.65	0.8	Ω

Note 1: Characteristic between Anode 1 and Anode 2

Note 2: Units are compounded in one package and are matched to 2.5%

$$\frac{\text{C (Max.)} - \text{C (Min.)}}{\text{C (Min.)}} \le 0.025 \quad \text{(VR=1~28V)}$$

Marking



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